NSN 5961-01-262-2869

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-262-2869 **Inclosure Material:** Glass or plastic **Overall Length:** Between 0.230 inches and 0.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.108 inches and 0.140 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 12.0 reverse voltage, dc **Current Rating Per Characteristic:** 250.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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